

## HIGH VOLTAGE FAST SWITCHING NPN POWER TRANSISTOR

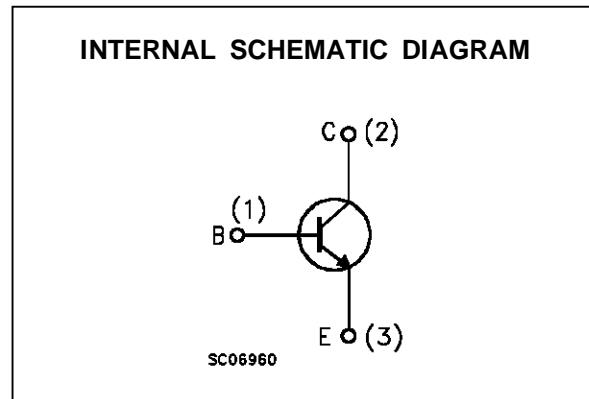
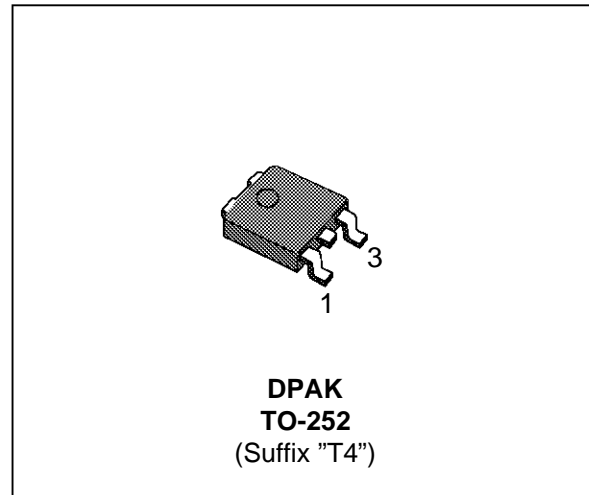
- SGS-THOMSON PREFERRED SALESTYPE
- HIGH VOLTAGE CAPABILITY
- SURFACE-MOUNTING TO-252 (DPAK)  
POWER PACKAGE IN TAPE & REEL  
(SUFFIX "T4")
- ELECTRICAL SIMILAR TO TIP47

### APPLICATIONS

- SWITCH MODE POWER SUPPLIES
- AUDIO AMPLIFIERS
- GENERAL PURPOSE SWITCHING AND  
AMPLIFIER

### DESCRIPTION

The MJD47 is manufactured using Medium Voltage Epitaxial Planar technology, resulting in a rugged high performance cost-effective transistor.



### ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
$V_{CB0}$	Collector-Base Voltage ( $I_E = 0$ )	350	V
$V_{CEO}$	Collector-Emitter Voltage ( $I_B = 0$ )	250	V
$V_{EBO}$	Emitter-Base Voltage ( $I_C = 0$ )	5	V
$I_C$	Collector Current	1	A
$I_{CM}$	Collector Peak Current ( $t_p < 5$ ms)	2	A
$I_B$	Base Current	0.6	A
$I_{BM}$	Base Peak Current ( $t_p < 5$ ms)	1.2	A
$P_{tot}$	Total Dissipation at $T_c = 25$ °C	15	W
$T_{stg}$	Storage Temperature	-65 to 150	°C
$T_j$	Max. Operating Junction Temperature	150	°C

# MJD47

## THERMAL DATA

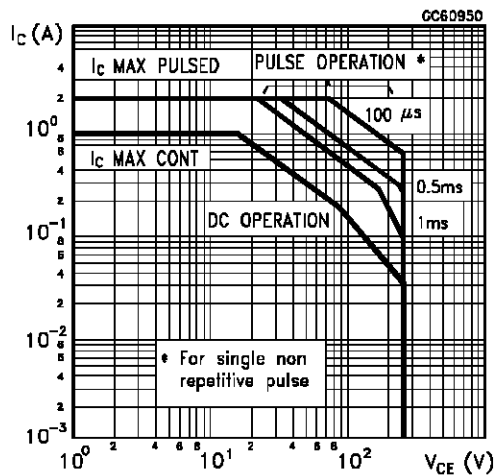
$R_{thj-case}$	Thermal Resistance Junction-case	Max	8.33	$^{\circ}C/W$
$R_{thj-amb}$	Thermal Resistance Junction-ambient	Max	100	$^{\circ}C/W$

## ELECTRICAL CHARACTERISTICS ( $T_{case} = 25^{\circ}C$ unless otherwise specified)

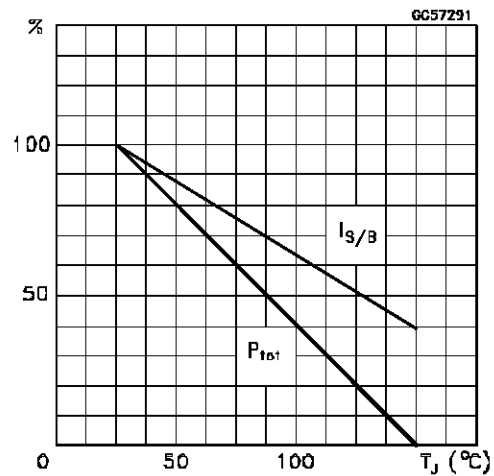
Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
$I_{CES}$	Collector Cut-off Current ( $V_{BE} = 0$ )	$V_{CE} = 350 V$			0.1	mA
$I_{CEO}$	Collector Cut-off Current ( $I_B = 0$ )	$V_{CE} = 150 V$			0.2	mA
$I_{EBO}$	Emitter Cut-off Current ( $I_C = 0$ )	$V_{EB} = 5 V$			1	mA
$V_{CEO(sus)}$	Collector-Emitter Sustaining Voltage	$I_C = 30 mA$	250			V
$V_{CE(sat)*}$	Collector-Emitter Saturation Voltage	$I_C = 1 A \quad I_B = 0.2 A$			1	V
$V_{BE(on)*}$	Base-Emitter On Voltage	$I_C = 1 A \quad V_{CE} = 10 V$			1.5	V
$h_{FE*}$	DC Current Gain	$I_C = 0.3 A \quad V_{CE} = 10 V$ $I_C = 1 A \quad V_{CE} = 10 V$	30 10		150	
$f_T$	Transition Frequency	$I_C = 200 mA \quad V_{CE} = 10 V \quad f=2MHz$	10			MHz
$h_{fe}$	Small Signal Current Gain	$I_C = 0.2 A \quad V_{CE} = 10 V \quad f=1kHz$	25			

\* Pulsed: Pulse duration = 300  $\mu s$ , duty cycle 1.5 %

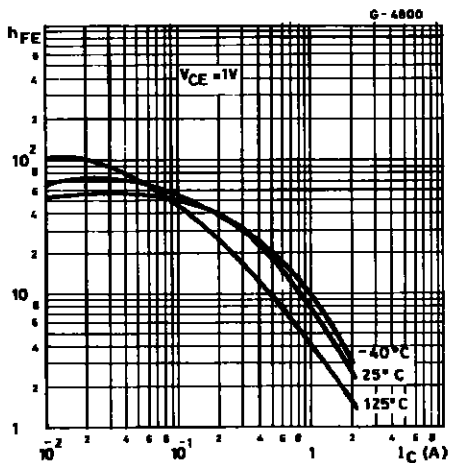
## Safe Operating Areas



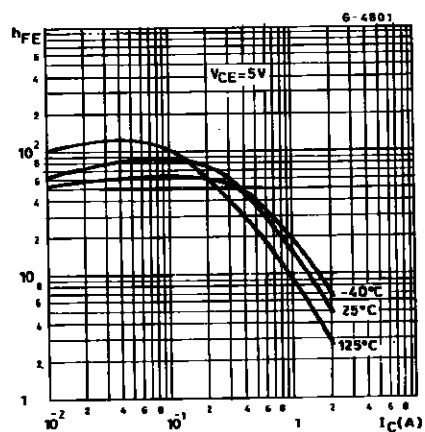
## Derating Curves



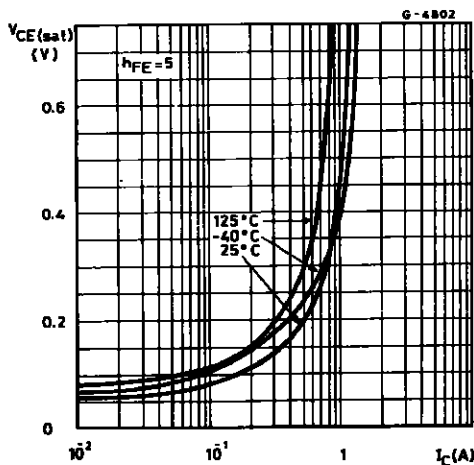
DC Current Gain



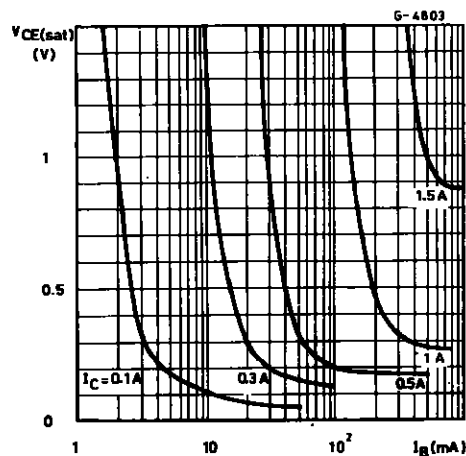
DC Current Gain



Collector-Emitter Saturation Voltage

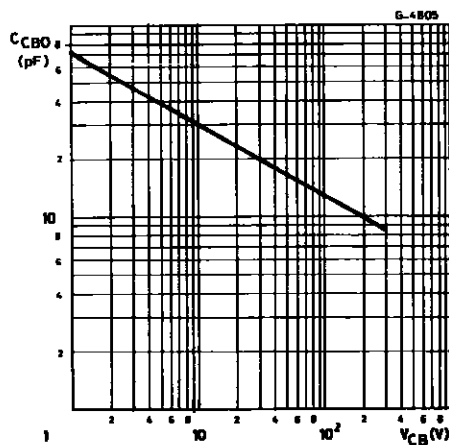
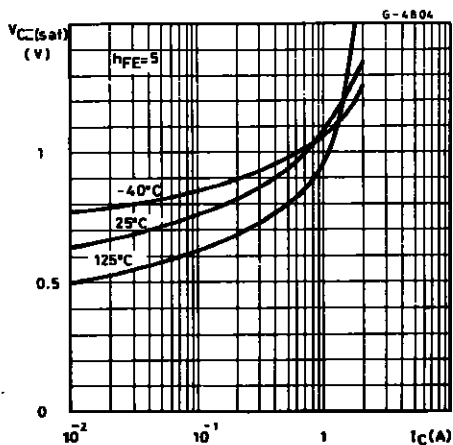


Collector-Emitter Saturation Voltage

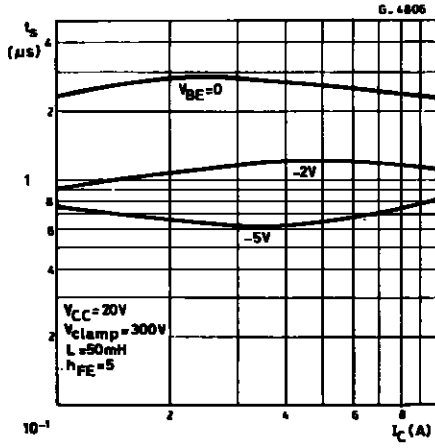


Base-Emitter Saturation Voltage

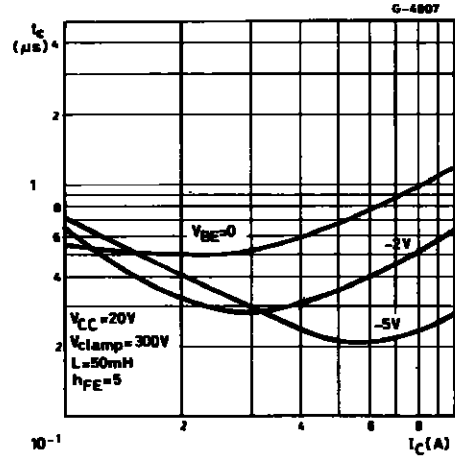
Collector-Base Capacitance



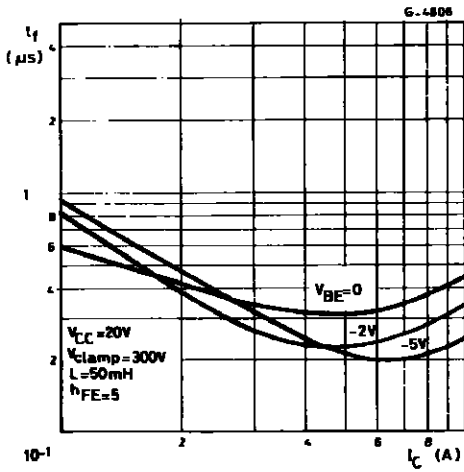
Switching Time Inductive Load



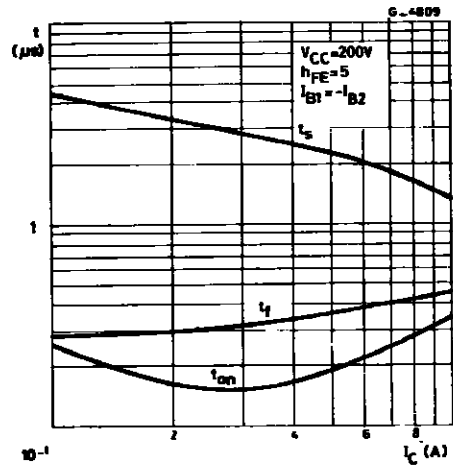
Switching Time Inductive Load



Switching Time Inductive Load

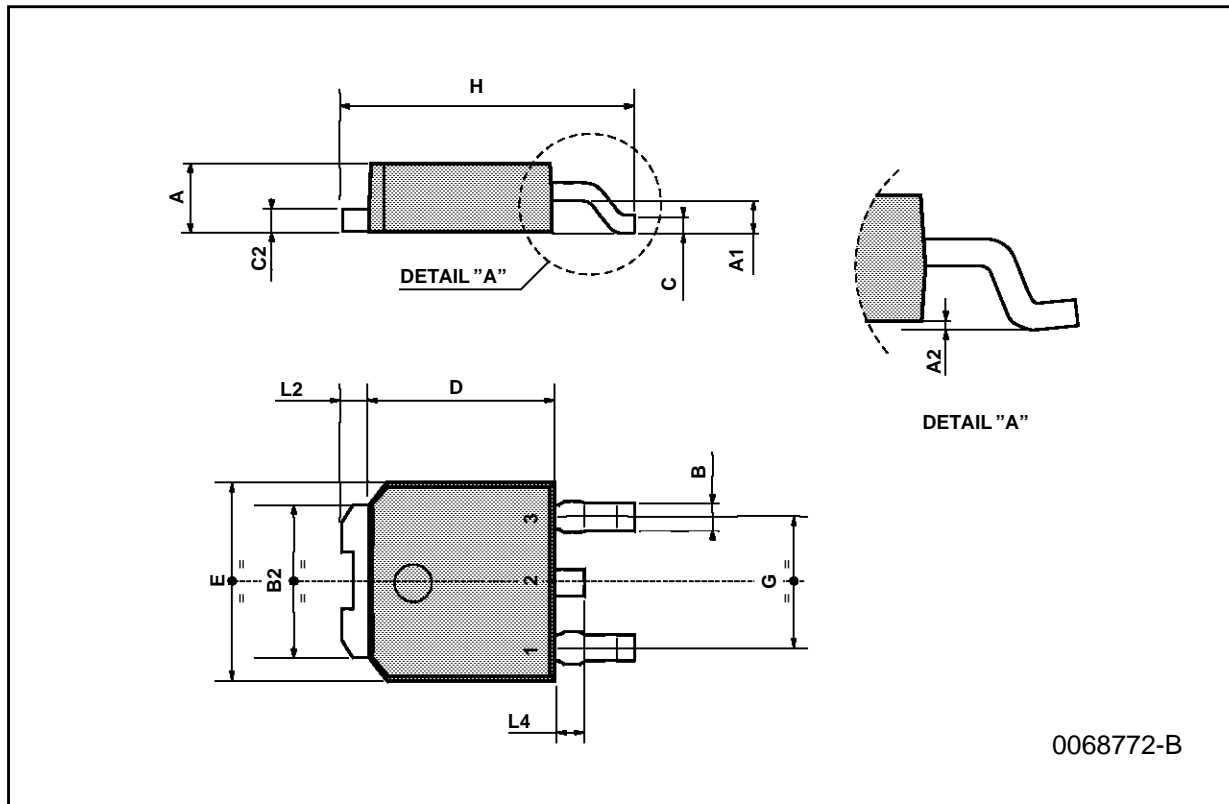


Switching Time Inductive Load



**TO-252 (DPAK) MECHANICAL DATA**

DIM.	mm			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
A	2.2		2.4	0.086		0.094
A1	0.9		1.1	0.035		0.043
A2	0.03		0.23	0.001		0.009
B	0.64		0.9	0.025		0.035
B2	5.2		5.4	0.204		0.212
C	0.45		0.6	0.017		0.023
C2	0.48		0.6	0.019		0.023
D	6		6.2	0.236		0.244
E	6.4		6.6	0.252		0.260
G	4.4		4.6	0.173		0.181
H	9.35		10.1	0.368		0.397
L2		0.8			0.031	
L4	0.6		1	0.023		0.039



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